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SILICON RECTIFIERS

25 Ampere Silicon Power Diodes

FEATURES

All Diffused Series

- ✤ Available in Normal & Reverse Polarity
- ✤ Industrial Grade
- Available In Avalanche Characteristic

DO-4

ELECTRICAL SPECIFICATIONS

25F/FR

IF(AV)	Maximum Average Forward Current Tc = 140°C	25A
Vfm	Maximum peak forward voltage drop @ Rated 1F(AV)	1.2 V
IFSM	Maximum peak one cycle (non-rep) surge current 10 msec	400 A
IFRM	Maximum peak repetive surge current	150 A
I2t	Maximum I ² t rating (non-rep.) for 5 to 10 msec.	800 A ² Sec

THERMAL MECHANICAL SPECIFICATIONS

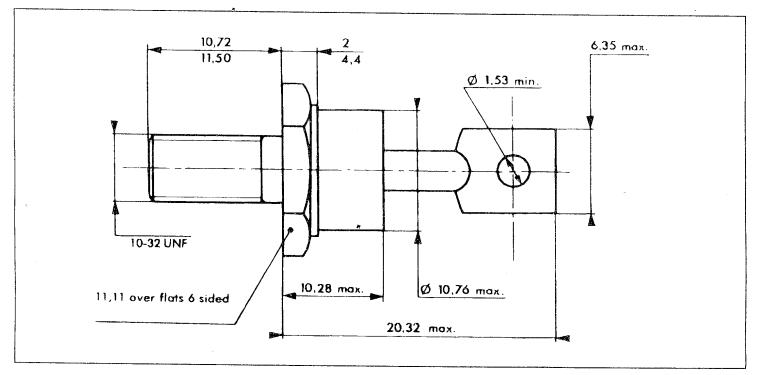
OJ-C	Maximum thermal resistance junction to case	0.80°C/W
TJ	Operating Junction Temp.	-65°C to 150°C
Tstg	Storage temperature.	-65C to 200°C
	Mounting torque	0.14 M-Kg min.
	(Non-lubricated threads)	0.17 M-kg max.
W	Approx. weight	7 gms.

ELECTRICAL RATING

ТҮРЕ	NUMBER 25F/FR	10	20	40	60	80	100	120	140	160
VRRMS	Max. repetitive peak voltage	100	200	400	600	800	1000	1200	1400	1600
VR(RMS)	Max.R.M.S Reverse Voltage (V)	70	140	280	420	560	700	840	980	1120
VR	Max. D.C. Blocking Voltage(V)	100	200	400	60	800	1000	1200	1400	1600
	Recommended R.M.S. working voltage (V)	40	80	160	240	320	400	480	560	640
IR(AV)	Max. Average reverse leakage current @VRRM Tc 25 Degree C (uA)	10	10	10	10	10	10	10	10	10

PACKAGE MECHANICAL DATA

DO 4 Metal



Marking : Cathode connected to case : type number Anode connected to case : type number + suffix R